TOSHIBA TRANSISTOR SILICON NPN EPITAXIAL PLANAR TYPE

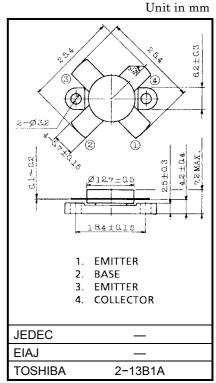
2SC2510

2~30MHz SSB LINEAR POWER AMPLIFIER APPLICATIONS (28V SUPPLY VOLTAGE USE)

- Specified 28V, 28MHz Characteristics
- Output Power $: Po = 150W_{PEP}$ (Min.)
- Power Gain : Gp = 12.2 dB (Min.)
- Collector Efficiency $: \eta_{\rm C} = 35\%$ (Min.)
- Intermodulation Distortion: IMD = -30dB (Max.)

MAXIMUM RATINGS (Tc = 25°C)

CHARACTERISTIC	SYMBOL	RATING	UNIT
Collector-Base Voltage	V _{CBO}	60	V
Collector-Emitter Voltage	V _{CES}	60	V
Collector-Emitter Voltage	V _{CEO}	35	V
Emitter-Base Voltage	V _{EBO}	4	V
Collector Current	۱ _C	20	А
Collector Power Dissipation	P _C	250	W
Junction Temperature	Тј	175	°C
Storage Temperature Range	T _{stg}	-65~175	°C



Weight: 5.2g

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ELECTRICAL CHARACTERISTICS (Tc = 25°C)

CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Collector-Emitter Breakdown Voltage	V (BR) CEO	I _C = 100mA, I _B = 0	35	_	_	V
Collector-Emitter Breakdown Voltage	V (BR) CES	I _C = 100mA, V _{EB} = 0	55	_	_	V
Emitter-Base Breakdown Voltage	V (BR) EBO	I _E = 1mA, I _C = 0	4	-		V
DC Current Gain	h _{FE}	V _{CE} = 5V, I _C = 10A *	10	_	_	
Collector Output Capacitance	C _{ob}	V _{CB} = 28V, I _E = 0 f = 1MHz	_	450	600	pF
Power Gain	Gp	V _{CC} = 28V, f ₁ = 28.000MHz, f ₂ = 28.001MHz	12.2	13.3		dB
Input Power	Pi			7	9	W_{PEP}
Collector Efficiency	η _C	I _{idle} = 100mA Po = 150W _{PEP} (Fig.)	35	_	_	%
Intermodulation Distortion	IMD			_	-30	dB
Series Equivalent Input Impedance	Z _{in}	V _{CC} = 28V, f ₁ = 28.000MHz, f ₂ = 28.001MHz,	_	1.4 −j0.9	_	Ω
Series Equivalent Output Impedance	Z _{out}	$P_0 = 150W_{PEP}$	_	2.3 -j0.9	_	Ω

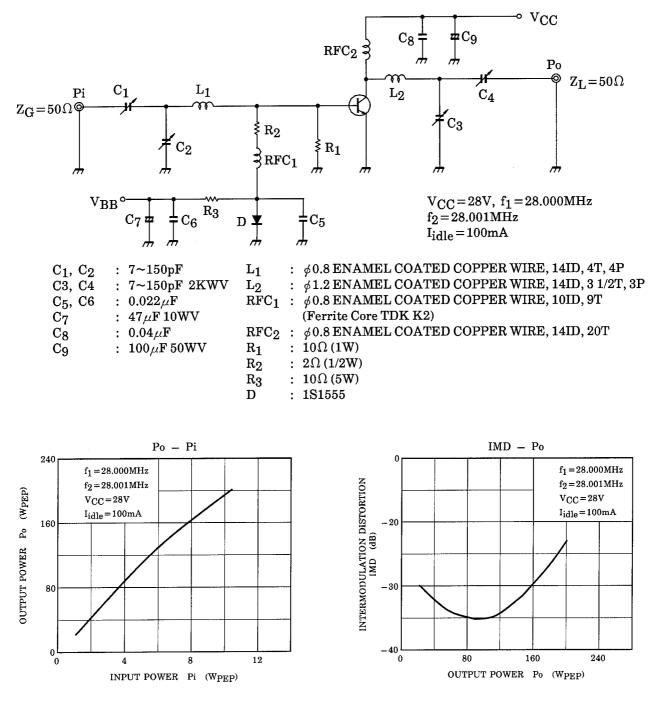
* Pulse Test: Pulse Width \leq 100µs, Duty Cycle \leq 3%

CAUTION

Beryllia Ceramics is used in this product. The dust or vapor can be dangerous to humans. Do not break, cut, crush or dissolve chemically. Dispose of this product properly according to law. Do not intermingle with normal industrial or domestic waste.

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Fig. Pi TEST CIRCUIT



CAUTION

These are only typical curves and devices are not necessarily guaranteed at these curves.